

# NTSX2102

Dual supply translating transceiver; open drain; auto direction sensing

Rev. 2 — 11 February 2013

Product data sheet

## 1. General description

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The NTSX2102 is a 2-bit, dual supply translating transceiver with auto direction sensing, that enables bidirectional voltage level translation. It features two 2-bit input-output ports (An and Bn), one output enable input (OE) and two supply pins ( $V_{CC(A)}$  and  $V_{CC(B)}$ ). Both supplies can be supplied at any voltage between 1.65 V and 5.5 V. This flexibility makes the device suitable for translating between any of the voltage nodes (1.8 V, 2.5 V, 3.3 V and 5.0 V). Pins An and OE are referenced to  $V_{CC(A)}$  and pins Bn are referenced to  $V_{CC(B)}$ . A LOW level at pin OE causes the outputs to assume a high-impedance OFF-state. This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

## 2. Features and benefits

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- Wide supply voltage range:
  - ◆  $V_{CC(A)}$ : 1.65 V to 5.5 V and  $V_{CC(B)}$ : 1.65 V to 5.5 V
- Maximum data rates:
  - ◆ 50 Mbps
- $I_{OFF}$  circuitry provides partial Power-down mode operation
- Inputs accept voltages up to 5.5 V
- ESD protection:
  - ◆ HBM JS-001 Class 2 exceeds 2000 V
  - ◆ CDM JESD22-C101E exceeds 2000 V
- Latch-up performance exceeds 100 mA per JESD 78B Class II
- Multiple package options
- Specified from  $-40\text{ }^{\circ}\text{C}$  to  $+85\text{ }^{\circ}\text{C}$

## 3. Applications

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- I<sup>2</sup>C/SMBus
- UART
- GPIO



4. Ordering information

Table 1. Ordering information

| Type number | Package           |       |                                                                                                  |           |
|-------------|-------------------|-------|--------------------------------------------------------------------------------------------------|-----------|
|             | Temperature range | Name  | Description                                                                                      | Version   |
| NTSX2102GM  | −40 °C to +85 °C  | XQFN8 | plastic extremely thin quad flat package; no leads; 8 terminals; body 1.6 × 1.6 × 0.5 mm         | SOT902-2  |
| NTSX2102GU8 | −40 °C to +85 °C  | XQFN8 | XQFN8: plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.4 × 1.2 × 0.5 mm | SOT1309-1 |
| NTSX2102GD  | −40 °C to +85 °C  | XSON8 | plastic extremely thin small outline package; no leads; 8 terminals; body 3 × 2 × 0.5 mm         | SOT996-2  |

5. Marking

Table 2. Marking

| Type number | Marking code |
|-------------|--------------|
| NTSX2102GM  | sX2          |
| NTSX2102GU8 | sX           |
| NTSX2102GD  | sX2          |

6. Functional diagram

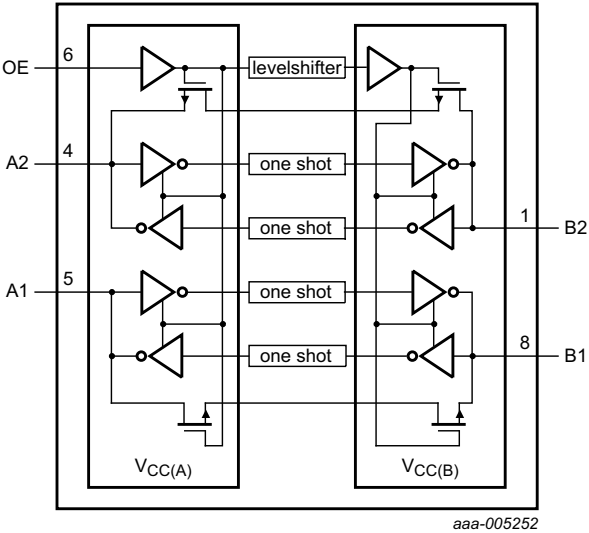
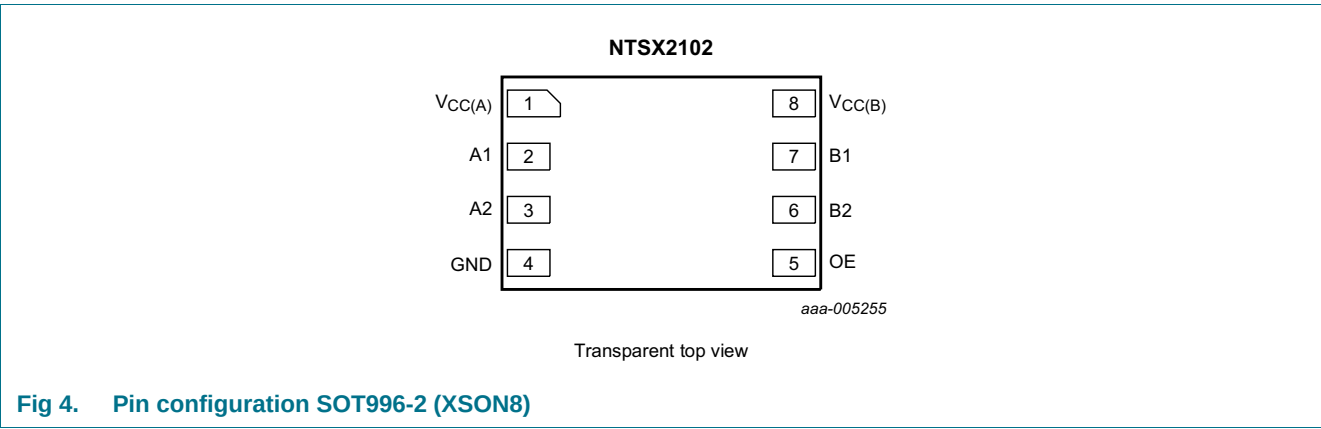
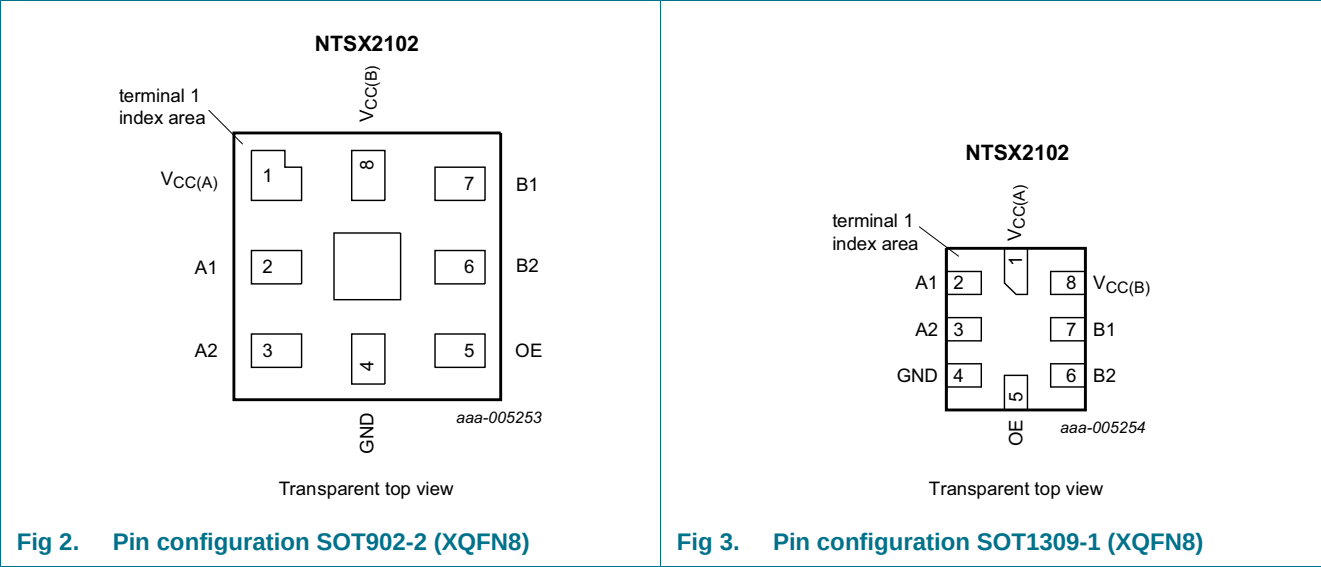


Fig 1. Logic symbol

7. Pinning information

7.1 Pinning



7.2 Pin description

Table 3. Pin description

| Symbol              | Pin  | Description                                                          |
|---------------------|------|----------------------------------------------------------------------|
| B2, B1              | 6, 7 | data input or output (referenced to V <sub>CC</sub> (B))             |
| GND                 | 4    | ground (0 V)                                                         |
| V <sub>CC</sub> (A) | 1    | supply voltage A                                                     |
| A2, A1              | 3, 2 | data input or output (referenced to V <sub>CC</sub> (A))             |
| OE                  | 5    | output enable input (active HIGH; referenced to V <sub>CC</sub> (A)) |
| V <sub>CC</sub> (B) | 8    | supply voltage B                                                     |

## 8. Functional description

Table 4. Function table<sup>[1]</sup>

| Supply voltage     |                    | Input | Input/output    |                 |
|--------------------|--------------------|-------|-----------------|-----------------|
| V <sub>CC(A)</sub> | V <sub>CC(B)</sub> | OE    | An              | Bn              |
| 1.65 V to 5.5 V    | 1.65 V to 5.5 V    | L     | Z               | Z               |
| 1.65 V to 5.5 V    | 1.65 V to 5.5 V    | H     | input or output | output or input |
| GND <sup>[2]</sup> | GND <sup>[2]</sup> | X     | Z               | Z               |

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

[2] When either V<sub>CC(A)</sub> or V<sub>CC(B)</sub> is at GND level, the device goes into power-down mode.

## 9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol             | Parameter               | Conditions                               | Min                    | Max                    | Unit |
|--------------------|-------------------------|------------------------------------------|------------------------|------------------------|------|
| V <sub>CC(A)</sub> | supply voltage A        |                                          | -0.5                   | +6.5                   | V    |
| V <sub>CC(B)</sub> | supply voltage B        |                                          | -0.5                   | +6.5                   | V    |
| V <sub>I</sub>     | input voltage           | A port and OE input                      | <sup>[1][2]</sup> -0.5 | +6.5                   | V    |
|                    |                         | B port                                   | <sup>[1][2]</sup> -0.5 | +6.5                   | V    |
| V <sub>O</sub>     | output voltage          | Active mode                              | <sup>[1][2]</sup>      |                        |      |
|                    |                         | A or B port                              | -0.5                   | V <sub>CCO</sub> + 0.5 | V    |
|                    |                         | Power-down or 3-state mode               | <sup>[1]</sup>         |                        |      |
|                    |                         | A or B port                              | -0.5                   | +6.5                   | V    |
| I <sub>IK</sub>    | input clamping current  | V <sub>I</sub> < 0 V                     | -50                    | -                      | mA   |
| I <sub>OK</sub>    | output clamping current | V <sub>O</sub> < 0 V                     | -50                    | -                      | mA   |
| I <sub>O</sub>     | output current          | V <sub>O</sub> = 0 V to V <sub>CCO</sub> | <sup>[2]</sup> -       | ±50                    | mA   |
| I <sub>CC</sub>    | supply current          | I <sub>CC(A)</sub> or I <sub>CC(B)</sub> | -                      | 100                    | mA   |
| I <sub>GND</sub>   | ground current          |                                          | -100                   | -                      | mA   |
| T <sub>stg</sub>   | storage temperature     |                                          | -65                    | +150                   | °C   |
| P <sub>tot</sub>   | total power dissipation | T <sub>amb</sub> = -40 °C to +85 °C      | -                      | 250                    | mW   |

[1] The minimum input and minimum output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] V<sub>CCO</sub> is the supply voltage associated with the output.

## 10. Recommended operating conditions

Table 6. Recommended operating conditions<sup>[1]</sup>

| Symbol             | Parameter        | Conditions | Min  | Max | Unit |
|--------------------|------------------|------------|------|-----|------|
| V <sub>CC(A)</sub> | supply voltage A |            | 1.65 | 5.5 | V    |
| V <sub>CC(B)</sub> | supply voltage B |            | 1.65 | 5.5 | V    |

**Table 6.** Recommended operating conditions<sup>[1]</sup> ...continued

| Symbol           | Parameter                           | Conditions                                                                    | Min | Max | Unit |
|------------------|-------------------------------------|-------------------------------------------------------------------------------|-----|-----|------|
| T <sub>amb</sub> | ambient temperature                 |                                                                               | -40 | +85 | °C   |
| Δt/ΔV            | input transition rise and fall rate | A, B or OE port                                                               |     |     |      |
|                  |                                     | V <sub>CC(A)</sub> = 1.65 V to 5.5 V;<br>V <sub>CC(B)</sub> = 1.65 V to 5.5 V | -   | 10  | ns/V |

[1] Hold the A and B sides of an unused I/O pair in the same state, both at V<sub>CCI</sub> or both at GND.

## 11. Static characteristics

**Table 7.** Typical static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); T<sub>amb</sub> = 25 °C.

| Symbol           | Parameter                | Conditions                                                          | Min | Typ | Max | Unit |
|------------------|--------------------------|---------------------------------------------------------------------|-----|-----|-----|------|
| C <sub>I</sub>   | input capacitance        | OE input; V <sub>CC(A)</sub> = V <sub>CC(B)</sub> = 0 V             | -   | 2.2 | -   | pF   |
| C <sub>I/O</sub> | input/output capacitance | A or B port; V <sub>CC(A)</sub> = 5.0 V; V <sub>CC(B)</sub> = 5.0 V | -   | 10  | -   | pF   |

[1] V<sub>CCO</sub> is the supply voltage associated with the output.

**Table 8.** Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter                 | Conditions                                                                                                                                     | -40 °C to +85 °C       |                        | Unit |
|------------------|---------------------------|------------------------------------------------------------------------------------------------------------------------------------------------|------------------------|------------------------|------|
|                  |                           |                                                                                                                                                | Min                    | Max                    |      |
| V <sub>IH</sub>  | HIGH-level input voltage  | A or B port                                                                                                                                    |                        |                        |      |
|                  |                           | V <sub>CC(A)</sub> = 1.65 V to 5.5 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V <sup>[1]</sup>                                                      | V <sub>CCI</sub> - 0.4 | -                      | V    |
|                  |                           | OE input                                                                                                                                       |                        |                        |      |
|                  |                           | V <sub>CC(A)</sub> = 1.65 V to 5.5 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V                                                                     | 0.65V <sub>CC(A)</sub> | -                      | V    |
| V <sub>IL</sub>  | LOW-level input voltage   | A or B port                                                                                                                                    |                        |                        |      |
|                  |                           | V <sub>CC(A)</sub> = 1.65 V to 5.5 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V                                                                     | -                      | 0.4                    | V    |
|                  |                           | OE input                                                                                                                                       |                        |                        |      |
|                  |                           | V <sub>CC(A)</sub> = 1.65 V to 5.5 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V                                                                     | -                      | 0.35V <sub>CC(A)</sub> | V    |
| V <sub>OL</sub>  | LOW-level output voltage  | A or B port; I <sub>O</sub> = 6 mA <sup>[2]</sup>                                                                                              |                        |                        |      |
|                  |                           | V <sub>I</sub> ≤ 0.15 V; V <sub>CC(A)</sub> = 1.65 V to 5.5 V;<br>V <sub>CC(B)</sub> = 1.65 V to 5.5 V                                         | -                      | 0.4                    | V    |
| I <sub>I</sub>   | input leakage current     | OE input; V <sub>I</sub> = 0 V to V <sub>CC(A)</sub> ; V <sub>CC(A)</sub> = 1.65 V to 5.5 V;<br>V <sub>CC(B)</sub> = 1.65 V to 5.5 V           | -                      | ±1                     | μA   |
| I <sub>OZ</sub>  | OFF-state output current  | A or B port; V <sub>O</sub> = 0 V or V <sub>CCO</sub> ; V <sub>CC(A)</sub> = 0 V to 5.5 V;<br>V <sub>CC(B)</sub> = 0 V to 5.5 V <sup>[2]</sup> | -                      | ±2                     | μA   |
| I <sub>OFF</sub> | power-off leakage current | A port; V <sub>I</sub> or V <sub>O</sub> = 0 V to 5.5 V;<br>V <sub>CC(A)</sub> = 0 V; V <sub>CC(B)</sub> = 0 V to 5.5 V                        | -                      | ±2                     | μA   |
|                  |                           | B port; V <sub>I</sub> or V <sub>O</sub> = 0 V to 5.5 V;<br>V <sub>CC(B)</sub> = 0 V; V <sub>CC(A)</sub> = 0 V to 5.5 V                        | -                      | ±2                     | μA   |

**Table 8.** Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol   | Parameter      | Conditions                                                                                                      | –40 °C to +85 °C |     | Unit          |
|----------|----------------|-----------------------------------------------------------------------------------------------------------------|------------------|-----|---------------|
|          |                |                                                                                                                 | Min              | Max |               |
| $I_{CC}$ | supply current | $V_I = 0\text{ V or }V_{CCI}$ ; $I_O = 0\text{ A}$ <a href="#">[1]</a>                                          |                  |     |               |
|          |                | $I_{CC(A)}$                                                                                                     |                  |     |               |
|          |                | $V_{CC(A)} = 1.65\text{ V to }5.5\text{ V}$ ; $V_{CC(B)} = 1.65\text{ V to }5.5\text{ V}$ ;<br>OE = LOW or HIGH | -                | 5   | $\mu\text{A}$ |
|          |                | $V_{CC(A)} = 1.65\text{ V to }5.5\text{ V}$ ; $V_{CC(B)} = 0\text{ V}$                                          | -                | 2   | $\mu\text{A}$ |
|          |                | $V_{CC(A)} = 0\text{ V}$ ; $V_{CC(B)} = 1.65\text{ V to }5.5\text{ V}$                                          | -                | -2  | $\mu\text{A}$ |
|          | $I_{CC(B)}$    | $V_{CC(A)} = 1.65\text{ V to }5.5\text{ V}$ ; $V_{CC(B)} = 1.65\text{ V to }5.5\text{ V}$ ;<br>OE = LOW         | -                | 5   | $\mu\text{A}$ |
|          |                | $V_{CC(A)} = 1.65\text{ V to }5.5\text{ V}$ ; $V_{CC(B)} = 0\text{ V}$                                          | -                | -2  | $\mu\text{A}$ |
|          |                | $V_{CC(A)} = 0\text{ V}$ ; $V_{CC(B)} = 1.65\text{ V to }5.5\text{ V}$                                          | -                | 2   | $\mu\text{A}$ |

[1]  $V_{CCI}$  is the supply voltage associated with the input.[2]  $V_{CCO}$  is the supply voltage associated with the output.

## 12. Dynamic characteristics

**Table 9.** Typical dynamic characteristics for temperature 25 °CVoltages are referenced to GND (ground = 0 V); for test circuit see [Figure 7](#); for waveforms see [Figure 5](#) and [Figure 6](#).

| Symbol    | Parameter                          | Conditions                                                                                                                       | $V_{CCO}$ <a href="#">[1]</a> |       |       |       | Unit |
|-----------|------------------------------------|----------------------------------------------------------------------------------------------------------------------------------|-------------------------------|-------|-------|-------|------|
|           |                                    |                                                                                                                                  | 1.8 V                         | 2.5 V | 3.3 V | 5.0 V |      |
| $t_{TLH}$ | LOW to HIGH output transition time | A or B port                                                                                                                      | 7                             | 5     | 4     | 3     | ns   |
| $t_{THL}$ | HIGH to LOW output transition time | A or B port                                                                                                                      | 4                             | 6     | 8     | 11    | ns   |
| $C_{PD}$  | power dissipation capacitance      | OE = $V_{CC(A)}$ ; $V_{CC(A)} = V_{CC(B)}$ ; <a href="#">[2]</a><br>$f_I = 400\text{ kHz}$ ; $V_I = V_{CCI}$ <a href="#">[3]</a> | -                             | -     | -     | 13.5  | pF   |

[1]  $V_{CCO}$  is the supply voltage associated with the output.[2]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where: $f_i$  = input frequency in MHz; $f_o$  = output frequency in MHz; $C_L$  = load capacitance in pF; $V_{CC}$  = supply voltage in V; $N$  = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.[3]  $V_{CCI}$  is the supply voltage associated with the input.

**Table 10. Dynamic characteristics for temperature range –40 °C to +85 °C<sup>[1]</sup>**

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 7](#); for wave forms see [Figure 5](#) and [Figure 6](#).

| Symbol                              | Parameter                          | Conditions       | V <sub>CC(B)</sub> |     |               |     |               |     |               |     | Unit |  |
|-------------------------------------|------------------------------------|------------------|--------------------|-----|---------------|-----|---------------|-----|---------------|-----|------|--|
|                                     |                                    |                  | 1.8 V ± 0.15 V     |     | 2.5 V ± 0.2 V |     | 3.3 V ± 0.3 V |     | 5.0 V ± 0.5 V |     |      |  |
|                                     |                                    |                  | Typ                | Max | Typ           | Max | Typ           | Max | Typ           | Max |      |  |
| V <sub>CC(A)</sub> = 1.8 V ± 0.15 V |                                    |                  |                    |     |               |     |               |     |               |     |      |  |
| t <sub>PHL</sub>                    | HIGH to LOW propagation delay      | A to B           | 3                  | 7   | 3             | 6   | 3             | 5   | 5             | 7   | ns   |  |
| t <sub>PLH</sub>                    | LOW to HIGH propagation delay      | A to B           | 5                  | 12  | 5             | 8   | 4             | 8   | 4             | 7   | ns   |  |
| t <sub>PHL</sub>                    | HIGH to LOW propagation delay      | B to A           | 3                  | 7   | 3             | 6   | 3             | 5   | 5             | 7   | ns   |  |
| t <sub>PLH</sub>                    | LOW to HIGH propagation delay      | B to A           | 5                  | 12  | 1             | 3   | 1             | 2   | 1             | 2   | ns   |  |
| t <sub>PZL</sub>                    | OFF-state to LOW propagation delay | OE to A          | 9                  | 16  | 9             | 18  | 10            | 14  | 10            | 15  | ns   |  |
|                                     |                                    | OE to B          | 9                  | 16  | 6             | 12  | 6             | 12  | 6             | 14  | ns   |  |
| t <sub>PLZ</sub>                    | LOW to OFF-state propagation delay | OE to A          | 100                | 120 | 100           | 120 | 100           | 120 | 100           | 120 | ns   |  |
|                                     |                                    | OE to B          | 100                | 120 | 100           | 120 | 100           | 120 | 100           | 120 | ns   |  |
| t <sub>sk(o)</sub>                  | output skew time                   | between channels | [2]                | -   | 1             | -   | 1             | -   | 1             | -   | 1 ns |  |
| f <sub>data</sub>                   | data rate                          |                  | -                  | 18  | -             | 18  | -             | 18  | -             | 18  | Mbps |  |
| V <sub>CC(A)</sub> = 2.5 V ± 0.2 V  |                                    |                  |                    |     |               |     |               |     |               |     |      |  |
| t <sub>PHL</sub>                    | HIGH to LOW propagation delay      | A to B           | 3                  | 6   | 2             | 5   | 2             | 5   | 2             | 5   | ns   |  |
| t <sub>PLH</sub>                    | LOW to HIGH propagation delay      | A to B           | 1                  | 3   | 2             | 4   | 2.5           | 7   | 2.5           | 5   | ns   |  |
| t <sub>PHL</sub>                    | HIGH to LOW propagation delay      | B to A           | 3                  | 6   | 2             | 5   | 2             | 5   | 2             | 5   | ns   |  |
| t <sub>PLH</sub>                    | LOW to HIGH propagation delay      | B to A           | 5                  | 8   | 2             | 4   | 1.5           | 3   | 1             | 3   | ns   |  |
| t <sub>PZL</sub>                    | OFF-state to LOW propagation delay | OE to A          | 6                  | 12  | 5             | 10  | 8             | 10  | 5             | 8   | ns   |  |
|                                     |                                    | OE to B          | 9                  | 18  | 5             | 10  | 4.5           | 9   | 4             | 8   | ns   |  |
| t <sub>PLZ</sub>                    | LOW to OFF-state propagation delay | OE to A          | 100                | 120 | 100           | 120 | 100           | 120 | 100           | 120 | ns   |  |
|                                     |                                    | OE to B          | 100                | 120 | 100           | 120 | 100           | 120 | 100           | 120 | ns   |  |
| t <sub>sk(o)</sub>                  | output skew time                   | between channels | [2]                | -   | 1             | -   | 1             | -   | 1             | -   | 1 ns |  |
| f <sub>data</sub>                   | data rate                          |                  | -                  | 18  | -             | 32  | -             | 32  | -             | 32  | Mbps |  |
| V <sub>CC(A)</sub> = 3.3 V ± 0.3 V  |                                    |                  |                    |     |               |     |               |     |               |     |      |  |
| t <sub>PHL</sub>                    | HIGH to LOW propagation delay      | A to B           | 3                  | 5   | 2             | 5   | 2             | 4   | 2             | 4   | ns   |  |
| t <sub>PLH</sub>                    | LOW to HIGH propagation delay      | A to B           | 1                  | 2   | 1.5           | 3   | 1.5           | 3   | 2             | 4   | ns   |  |
| t <sub>PHL</sub>                    | HIGH to LOW propagation delay      | B to A           | 3                  | 5   | 2             | 5   | 2             | 4   | 2             | 4   | ns   |  |
| t <sub>PLH</sub>                    | LOW to HIGH propagation delay      | B to A           | 4                  | 8   | 2.5           | 7   | 1.5           | 3   | 1             | 3   | ns   |  |
| t <sub>PZL</sub>                    | OFF-state to LOW propagation delay | OE to A          | 6                  | 12  | 4.5           | 9   | 6             | 9   | 4             | 7   | ns   |  |
|                                     |                                    | OE to B          | 10                 | 14  | 5             | 10  | 6             | 9   | 4             | 8   | ns   |  |

**Table 10. Dynamic characteristics for temperature range  $-40\text{ }^{\circ}\text{C}$  to  $+85\text{ }^{\circ}\text{C}$ <sup>[1]</sup>**

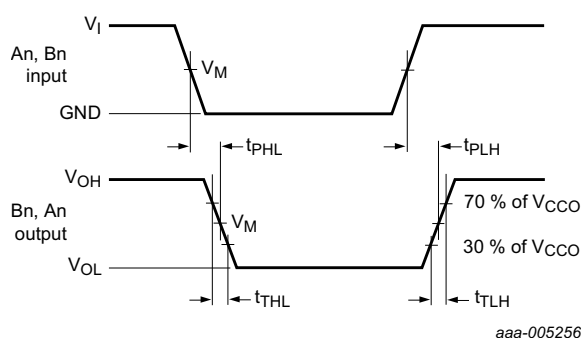
Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 7](#); for wave forms see [Figure 5](#) and [Figure 6](#).

| Symbol                             | Parameter                          | Conditions       | V <sub>CC(B)</sub> |     |               |     |               |     |               |     | Unit |      |
|------------------------------------|------------------------------------|------------------|--------------------|-----|---------------|-----|---------------|-----|---------------|-----|------|------|
|                                    |                                    |                  | 1.8 V ± 0.15 V     |     | 2.5 V ± 0.2 V |     | 3.3 V ± 0.3 V |     | 5.0 V ± 0.5 V |     |      |      |
|                                    |                                    |                  | Typ                | Max | Typ           | Max | Typ           | Max | Typ           | Max |      |      |
| t <sub>PLZ</sub>                   | LOW to OFF-state propagation delay | OE to A          | 100                | 120 | 100           | 120 | 100           | 120 | 100           | 120 | ns   |      |
|                                    |                                    | OE to B          | 100                | 120 | 100           | 120 | 100           | 120 | 100           | 120 | ns   |      |
| t <sub>sk(o)</sub>                 | output skew time                   | between channels | [2]                | -   | 1             | -   | 1             | -   | 1             | -   | 1    | ns   |
| f <sub>data</sub>                  | data rate                          |                  |                    | -   | 18            | -   | 32            | -   | 40            | -   | 40   | Mbps |
| V <sub>CC(A)</sub> = 5.0 V ± 0.5 V |                                    |                  |                    |     |               |     |               |     |               |     |      |      |
| t <sub>PHL</sub>                   | HIGH to LOW propagation delay      | A to B           |                    | 5   | 7             | 2   | 5             | 2   | 4             | 2   | 4    | ns   |
| t <sub>PLH</sub>                   | LOW to HIGH propagation delay      | A to B           |                    | 1   | 2             | 1   | 3             | 1   | 3             | 1   | 3    | ns   |
| t <sub>PHL</sub>                   | HIGH to LOW propagation delay      | B to A           |                    | 5   | 7             | 2   | 5             | 2   | 4             | 2   | 4    | ns   |
| t <sub>PLH</sub>                   | LOW to HIGH propagation delay      | B to A           |                    | 4   | 7             | 2.5 | 5             | 2   | 4             | 1   | 3    | ns   |
| t <sub>PZL</sub>                   | OFF-state to LOW propagation delay | OE to A          |                    | 6   | 14            | 4   | 8             | 4   | 8             | 3   | 5    | ns   |
|                                    |                                    | OE to B          |                    | 10  | 15            | 5   | 8             | 4   | 7             | 4   | 5    | ns   |
| t <sub>PLZ</sub>                   | LOW to OFF-state propagation delay | OE to A          |                    | 100 | 120           | 100 | 120           | 100 | 120           | 100 | 120  | ns   |
|                                    |                                    | OE to B          |                    | 100 | 120           | 100 | 120           | 100 | 120           | 100 | 120  | ns   |
| t <sub>sk(o)</sub>                 | output skew time                   | between channels | [2]                | -   | 1             | -   | 1             | -   | 1             | -   | 1    | ns   |
| f <sub>data</sub>                  | data rate                          |                  |                    | -   | 18            | -   | 32            | -   | 40            | -   | 52   | Mbps |

[1] All typical values are measured at nominal  $V_{CC}$  and  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

[2] Skew between any two outputs of the same package switching in the same direction.

## 13. Waveforms



Measurement points are given in [Table 11](#).

$V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

**Fig 5. The data input (An, Bn) to data output (Bn, An) propagation delay times**



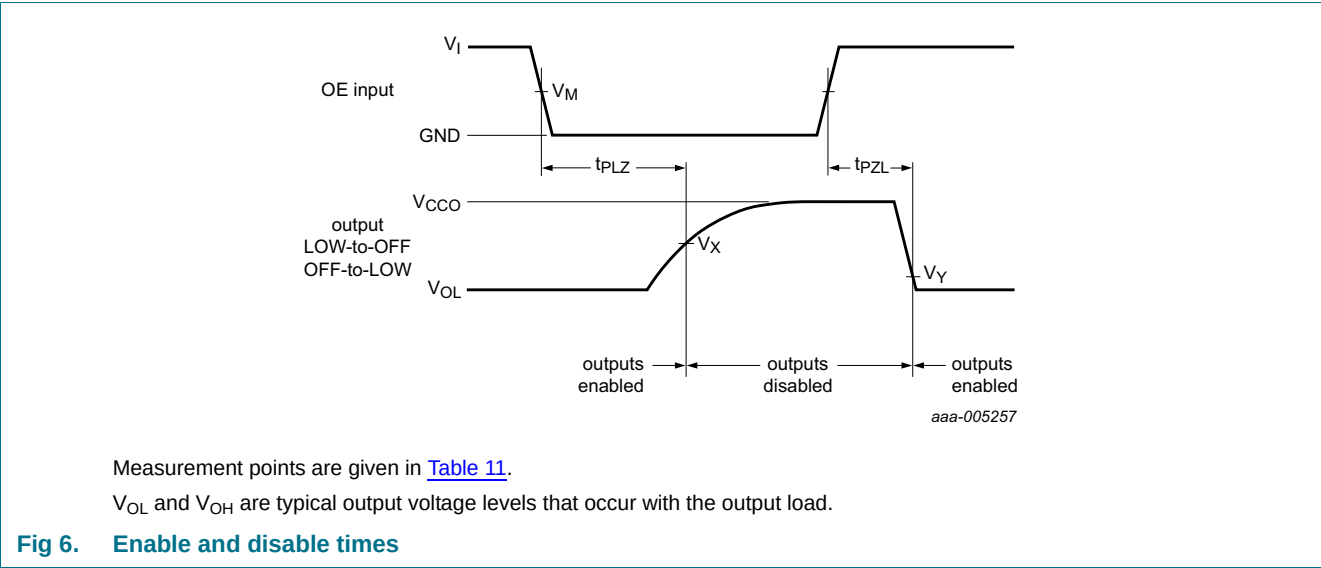
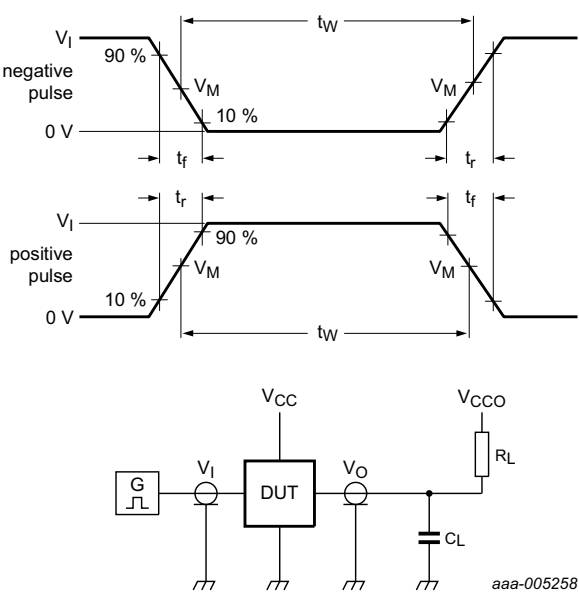


Table 11. Measurement points<sup>[1][2]</sup>

| Supply voltage  | Input        | Output       |              |              |
|-----------------|--------------|--------------|--------------|--------------|
| $V_{CCO}$       | $V_M$        | $V_M$        | $V_X$        | $V_Y$        |
| 1.65 V to 5.5 V | $0.5V_{CCI}$ | $0.5V_{CCO}$ | $0.5V_{CCO}$ | $0.1V_{CCO}$ |

- [1]  $V_{CCI}$  is the supply voltage associated with the input.
- [2]  $V_{CCO}$  is the supply voltage associated with the output.



Test data is given in [Table 12](#).  
All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz; Z<sub>O</sub> = 50 Ω; dV/dt ≥ 1.0 V/ns.  
R<sub>L</sub> = Load resistance.  
C<sub>L</sub> = Load capacitance including jig and probe capacitance.  
V<sub>CC0</sub> = Supply voltage associated with the output.

Fig 7. Test circuit for measuring switching times

Table 12. Test data

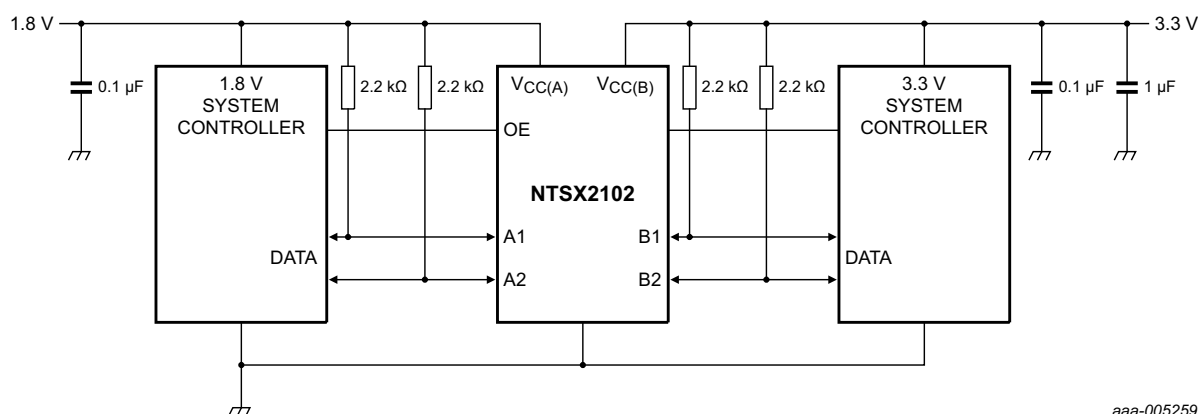
| Supply voltage     |                    | Input                         |                                | Load           |                |
|--------------------|--------------------|-------------------------------|--------------------------------|----------------|----------------|
| V <sub>CC(A)</sub> | V <sub>CC(B)</sub> | V <sub>I</sub> <sup>[1]</sup> | t <sub>r</sub> /t <sub>f</sub> | C <sub>L</sub> | R <sub>L</sub> |
| 1.65 V to 1.95 V   | 1.65 V to 1.95 V   | V <sub>CCI</sub>              | ≤ 2.0 ns                       | 50 pF          | 2.2 kΩ         |
| 2.3 V to 2.7 V     | 2.3 V to 2.7 V     | V <sub>CCI</sub>              | ≤ 2.0 ns                       | 50 pF          | 2.2 kΩ         |
| 3.0 V to 3.6 V     | 3.0 V to 3.6 V     | V <sub>CCI</sub>              | ≤ 2.5 ns                       | 50 pF          | 2.2 kΩ         |
| 4.5 V to 5.5 V     | 4.5 V to 5.5 V     | V <sub>CCI</sub>              | ≤ 2.5 ns                       | 50 pF          | 2.2 kΩ         |

[1] V<sub>CCI</sub> is the supply voltage associated with the input.

## 14. Application information

### 14.1 Applications

The NTSX2102 can be used in point-to-point applications to interface between devices or systems operating at different supply voltages. The device is targeted at I<sup>2</sup>C or 1-wire buses which use open-drain drivers.



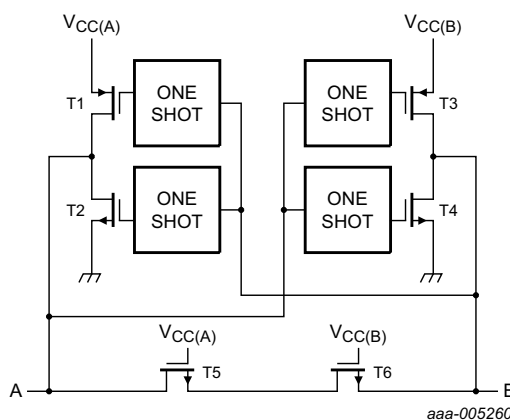
aaa-005259

Fig 8. Typical voltage level-translation circuit

### 14.2 Architecture

The architecture of the NTSX2102 is shown in Figure 9. The device does not require an extra input signal to control the direction of data flow from A to B or B to A. The NTSX2102 is a "switch" type voltage translator, it employs two key circuits to enable voltage translation:

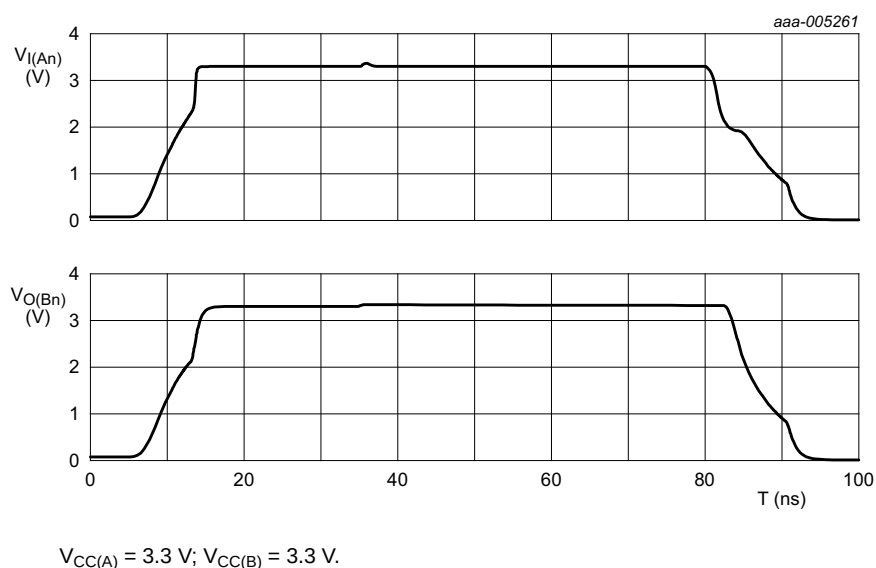
1. Two pass-gate transistors (N-channel) that tie the ports together.
2. An output edge-rate accelerator that detects and accelerates rising and falling edges on the I/O pins (see Figure 10).



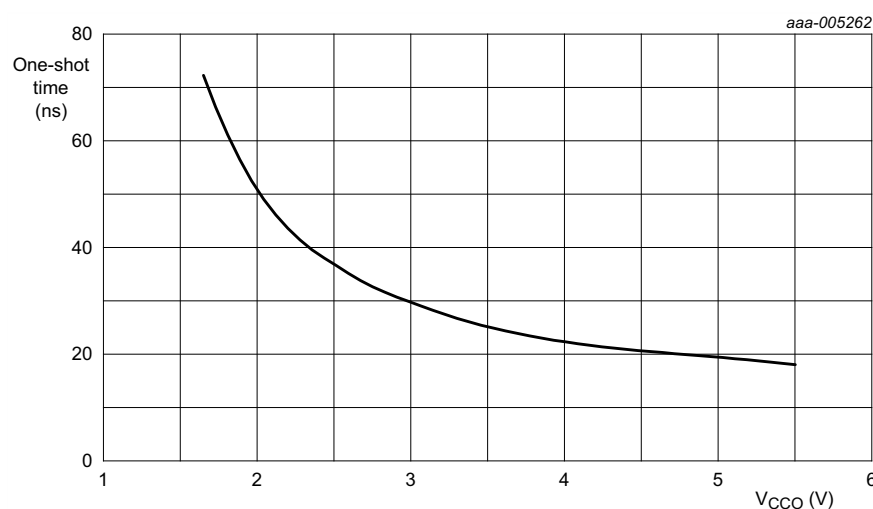
aaa-005260

Fig 9. Architecture of NTSX2102 I/O cell (one channel)

During an input transition, a one-shot accelerates the output transition by switching on the PMOS transistors (T1, T3) for a LOW-to-HIGH transition. Alternatively, it switches on the NMOS transistors (T2, T4) for a HIGH-to-LOW transition. Once activated, the one-shot is de-activated after approximately 25 ns (see [Figure 11](#)). During the acceleration time, the driver output resistance is between approximately 10  $\Omega$  and 35  $\Omega$ . To avoid signal contention, the application must not exceed the maximum data rate or wait for the one-shot circuit to turn-off, before applying a signal in the opposite direction.



**Fig 10. Input and output waveforms showing edge-rate acceleration**



**Fig 11. One-shot pulse time versus  $V_{CCO}$**

### 14.3 Input driver requirements

As the NTSX2102 is a switch type translator, properties of the input driver directly affect the output signal. The external open-drain driver applied to an I/O, determines the static current sinking capability of the system. The maximum data rate, output transition times ( $t_{THL}$ ,  $t_{TLH}$ ) and propagation delays ( $t_{PHL}$ ,  $t_{PLH}$ ) are dependent upon the output impedance and edge-rate of the external driver.

### 14.4 Output load considerations

The maximum lumped capacitive load that can be driven is dependent upon the one-shot pulse duration and has been tuned to 600 pF. In cases with higher capacitive loading, there is a risk that the output does not reach the positive rail within the one-shot pulse duration. To avoid excessive capacitive loading and to ensure correct triggering of the one-shot, use short trace lengths and low capacitance connectors on NTSX2102 PCB layouts. The length of the PCB trace should be such that the round-trip delay of any reflection is within the one-shot pulse duration. Such a length ensures low impedance termination and avoids output signal oscillations and one-shot retriggering.

### 14.5 Output enable (OE)

An output enable input (OE) is used to disable the device. Setting OE = LOW causes all I/Os to assume the high-impedance OFF-state.

### 14.6 Power-up

When either of the supplies  $V_{CC(n)}$  is at 0 V, outputs are in the high-impedance OFF-state. One of the advantages of NTSX translators is that either  $V_{CC(A)}$  or  $V_{CC(B)}$  may be powered up first. To reduce dissipation during power-up, ensure that output enable (OE) is defined. Connect it via a pull down resistor to GND or, if the application allows, hardwired to  $V_{CC(A)}$ . If the OE pin is hardwired to  $V_{CC(A)}$ , either supply can be powered up or down first. If a pull down is used, the following sequences are recommended.

For power-up:

1. Apply power to either supply pin
2. Apply power to other supply pin
3. Enable the device by driving OE HIGH

For power down:

1. Disable the device by driving OE LOW
2. Remove power from either supply pin
3. Remove power from other supply pin

### 14.7 Pull-up resistors on I/O lines

Each A port I/O requires a pull-up resistor to  $V_{CC(A)}$ , and each B port I/O requires a pull-up resistor to  $V_{CC(B)}$ . Choose the magnitude of the pull-up resistors to ensure that the output voltage levels meet the application requirement.

15. Package outline

XQFN8: plastic, extremely thin quad flat package; no leads;  
8 terminals; body 1.6 x 1.6 x 0.5 mm

SOT902-2

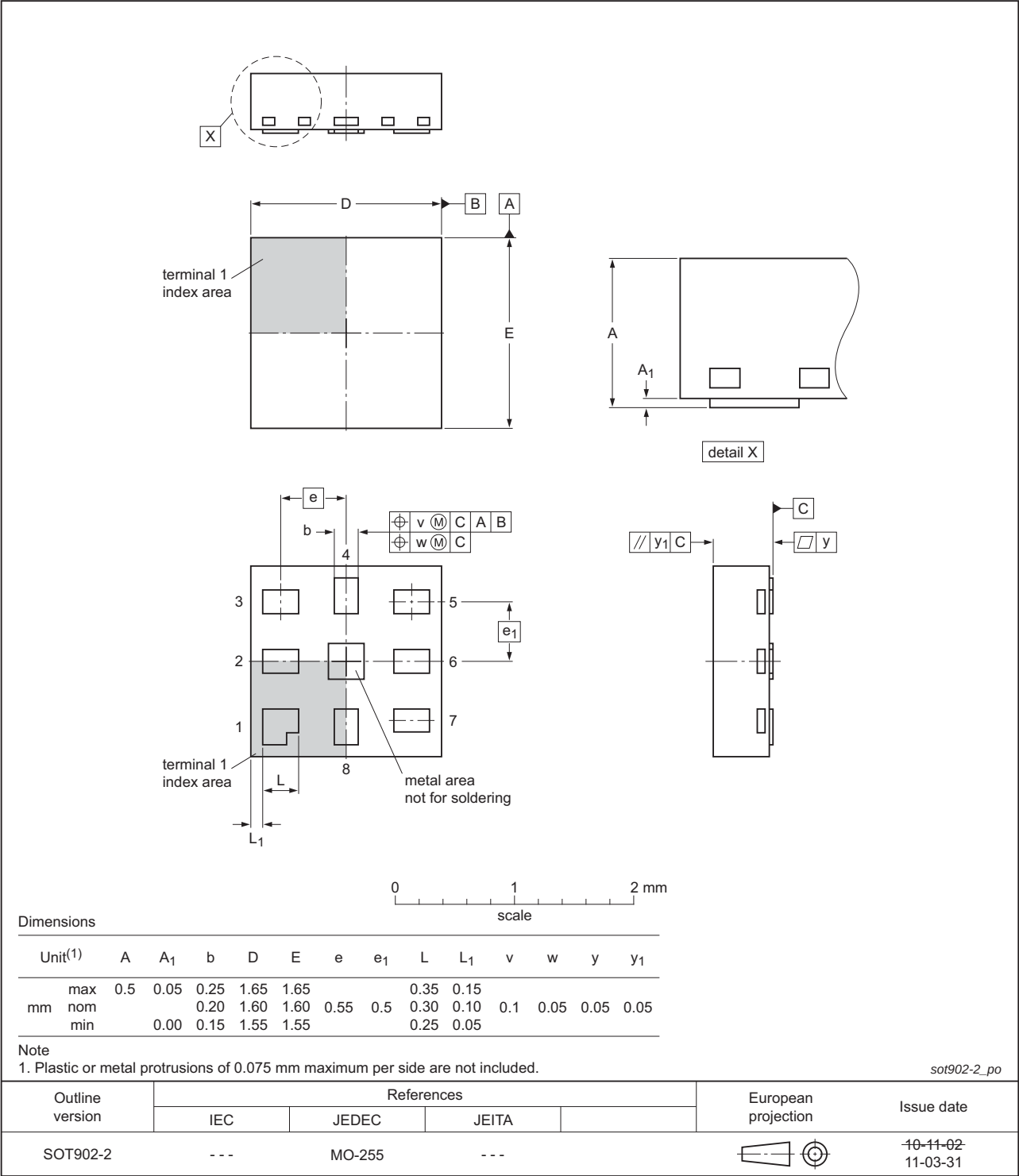


Fig 12. Package outline SOT902-2 (XQFN8)

XQFN8: plastic, extremely thin quad flat package; no leads;  
8 terminals; body 1.4 x 1.2 x 0.5 mm

SOT1309-1

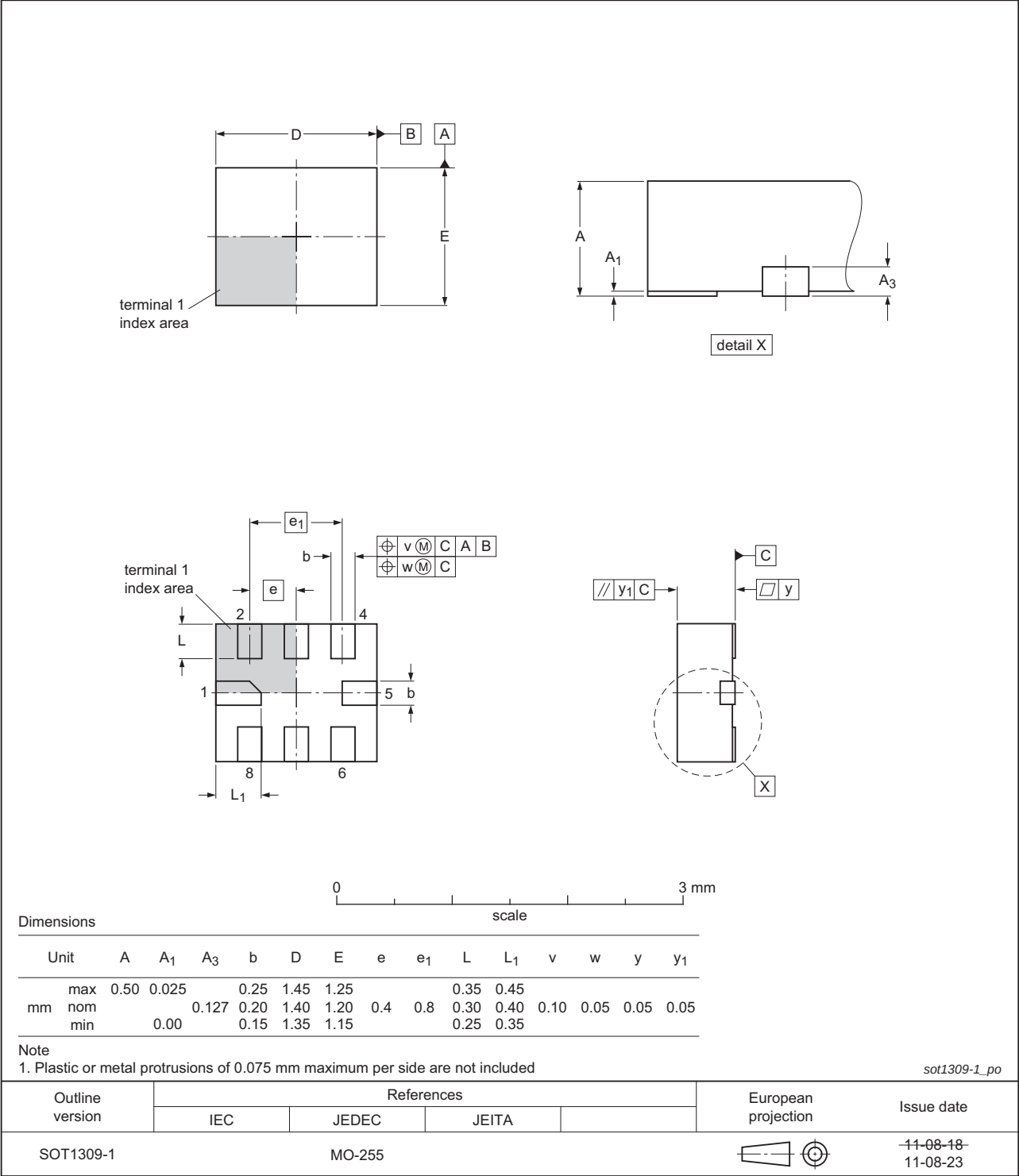


Fig 13. Package outline SOT1309-1 (XQFN8)

XSON8: plastic extremely thin small outline package; no leads;  
8 terminals; body 3 x 2 x 0.5 mm

SOT996-2

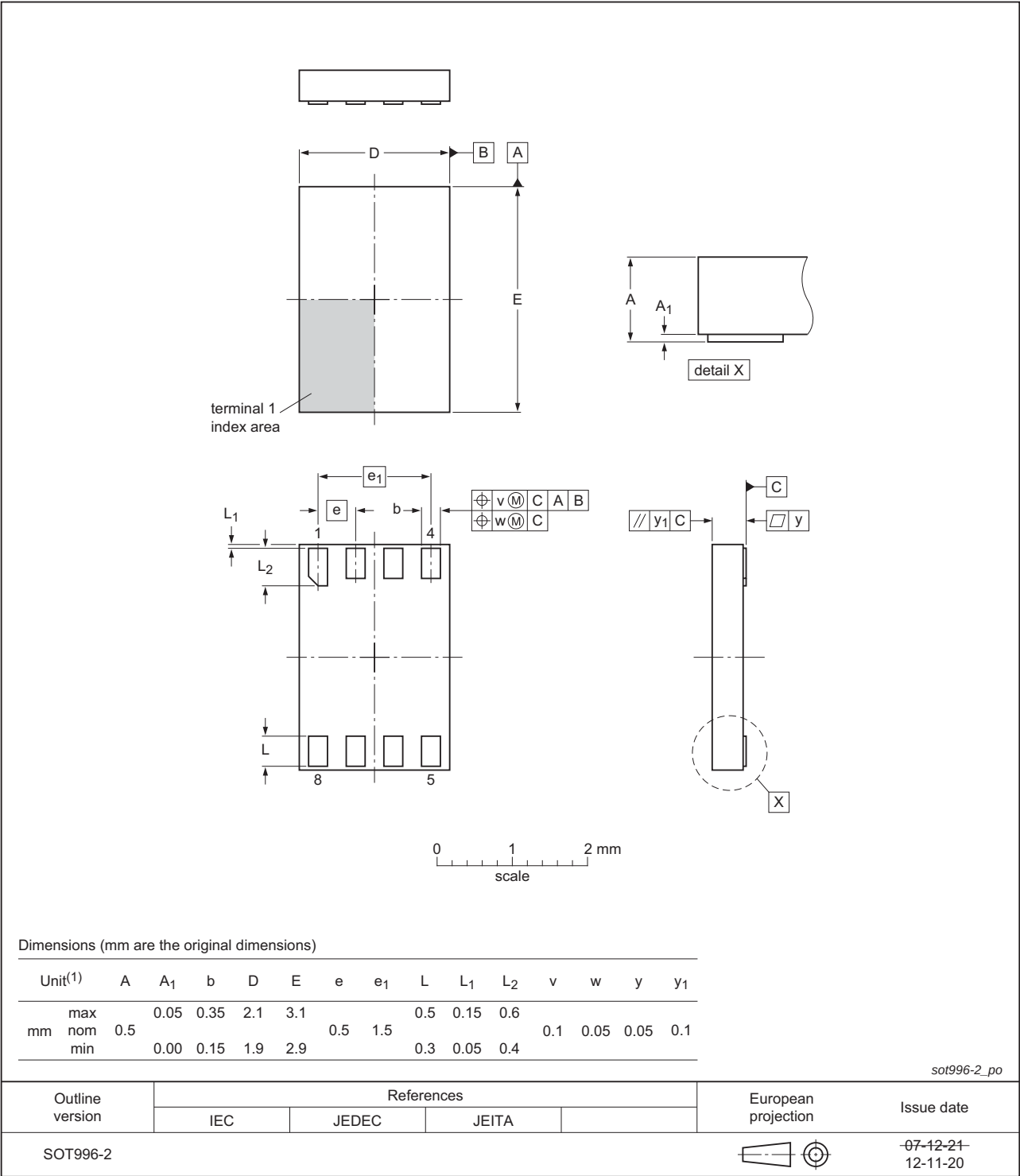


Fig 14. Package outline SOT996-2 (XSON8)



## 16. Abbreviations

Table 13. Abbreviations

| Acronym          | Description                                 |
|------------------|---------------------------------------------|
| CDM              | Charged Device Model                        |
| CMOS             | Complementary Metal Oxide Semiconductor     |
| DUT              | Device Under Test                           |
| ESD              | ElectroStatic Discharge                     |
| GPIO             | General Purpose Input Output                |
| HBM              | Human Body Model                            |
| I <sup>2</sup> C | Inter-Integrated Circuit                    |
| PCB              | Printed Circuit Board                       |
| PMOS             | Positive Metal Oxide Semiconductor          |
| SMBus            | System Management Bus                       |
| UART             | Universal Asynchronous Receiver Transmitter |
| UTLP             | Ultra Thin Leadless Package                 |

## 17. Revision history

Table 14. Revision history

| Document ID    | Release date                                                    | Data sheet status  | Change notice | Supersedes     |
|----------------|-----------------------------------------------------------------|--------------------|---------------|----------------|
| NTSX2102 v.2   | 20130211                                                        | Product data sheet | -             | NTSX2102 v.1.1 |
| Modifications: | • For type number NTSX2102GD XSON8U has changed to XSON8.       |                    |               |                |
| NTSX2102 v.1.1 | 20121121                                                        | Product data sheet | -             | NTSX2102 v.1   |
| Modifications: | • <a href="#">Section 1 “General description”</a> text updated. |                    |               |                |
| NTSX2102 v.1   | 20121119                                                        | Product data sheet | -             | -              |

## 18. Legal information

### 18.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition                                                                            |
|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Date of release: 11 February 2013

Document identifier: NTSX2102



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